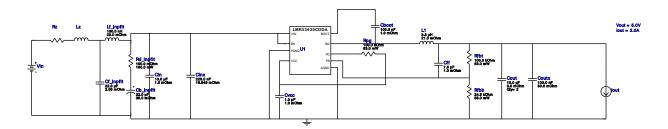


WEBENCH® Design Report

VinMin = 18.0V VinMax = 30.0V Vout = 5.0V Iout = 2.0A Device = LMR33630CDDAR Topology = Buck Created = 2020-07-19 08:35:56.915 BOM Cost = \$2.36 BOM Count = 17 Total Pd = 1.92W

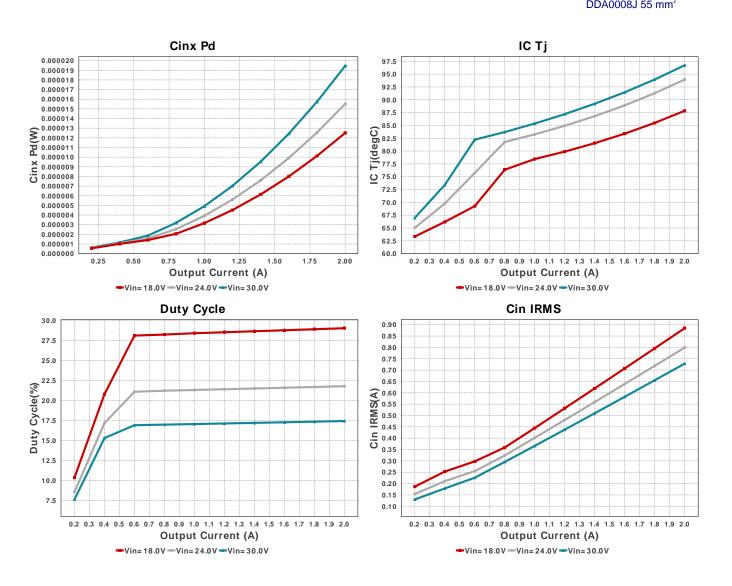
Design: 79 LMR33630CDDAR LMR33630CDDAR 18V-30V to 5.00V @ 2A

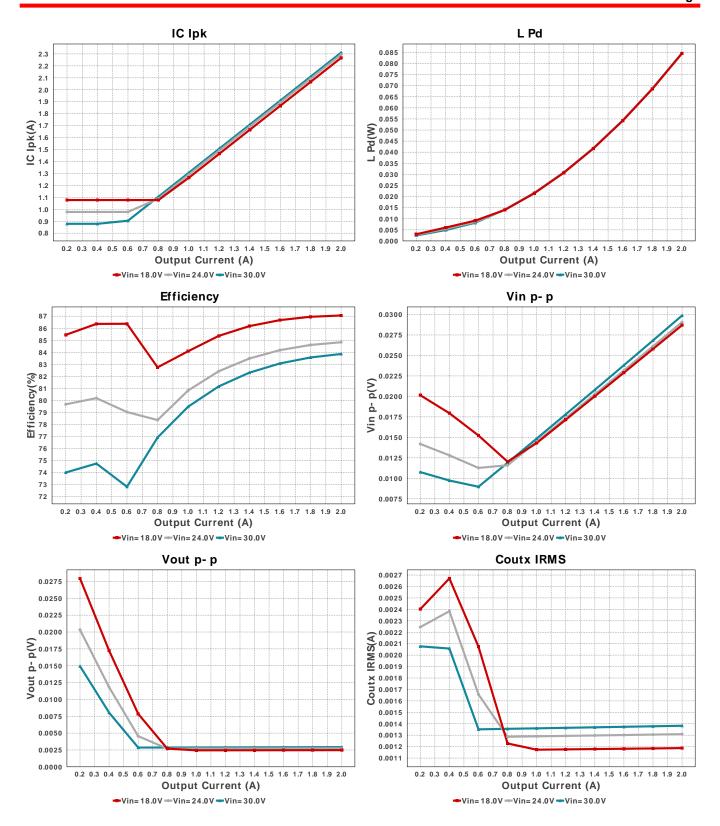


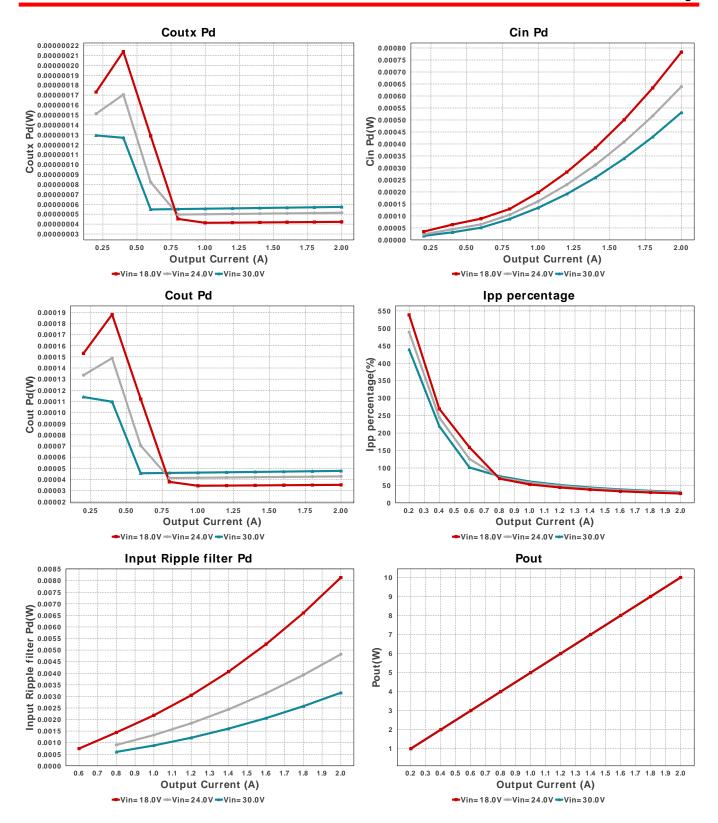
## **Electrical BOM**

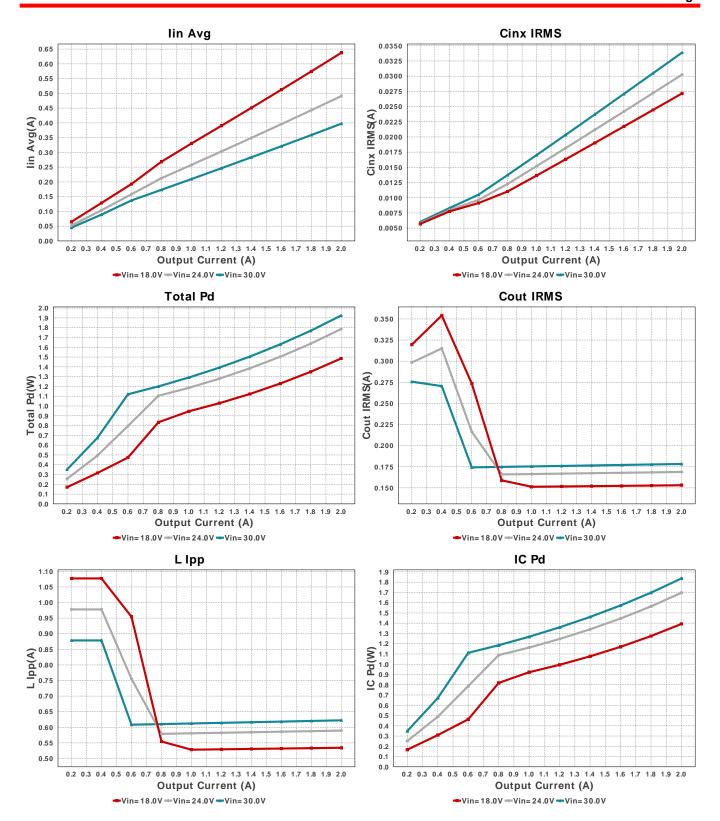
Name	Manufacturer	Part Number	Properties	Qty	Price	Footprint
Cb_inpflt	Panasonic	35SVPF22M Series= SVPF	Cap= 22.0 uF ESR= 35.0 mOhm VDC= 35.0 V IRMS= 2.6 A	1	\$0.44	CAPSMT_62_F61 74 mm <sup>2</sup>
Cboot	MuRata	GRM155R71C104KA88D Series= X7R	Cap= 100.0 nF ESR= 1.0 mOhm VDC= 16.0 V IRMS= 0.0 A	1	\$0.01	0402 3 mm <sup>2</sup>
Cf_inpflt	TDK	C2012X5R1V226M125AC Series= X5R	Cap= 22.0 uF ESR= 2.05 mOhm VDC= 35.0 V IRMS= 4.5559 A	1	\$0.33	0805 7 mm <sup>2</sup>
Cff	MuRata	GRM1555C1H7R5CA01D Series= C0G/NP0	Cap= 7.5 pF ESR= 1.0 mOhm VDC= 50.0 V IRMS= 0.0 A	1	\$0.01	0402 3 mm <sup>2</sup>
Cff	MuRata	GRM1555C1H7R5CA01D Series= C0G/NP0	Cap= 7.5 pF ESR= 1.0 mOhm VDC= 50.0 V IRMS= 0.0 A	1	\$0.01	0402 3 mm <sup>2</sup>
Cin	TDK	C3225X7R1H106M250AC Series= X7R	Cap= 10.0 uF ESR= 1.0 mOhm VDC= 50.0 V IRMS= 5.0 A	1	\$0.28	1210 15 mm <sup>2</sup>
Cinx	TDK	C2012X7R1H224K125AA Series= X7R	Cap= 220.0 nF ESR= 16.949 mOhm VDC= 50.0 V IRMS= 1.5961 A	1	\$0.03	0805 7 mm <sup>2</sup>
Cout	Kemet	C0805C106K8PACTU Series= X5R	Cap= 10.0 uF ESR= 3.0 mOhm VDC= 10.0 V IRMS= 11.43 A	2	\$0.03	0805 7 mm <sup>2</sup>
Coutx	MuRata	GRM188R71E104KA01D Series= X7R	Cap= 100.0 nF ESR= 30.0 mOhm VDC= 25.0 V IRMS= 1.51 A	1	\$0.01	0603 5 mm <sup>2</sup>
Cvcc	Kemet	C0603C105K8PACTU Series= X5R	Cap= 1.0 uF ESR= 1.0 mOhm VDC= 10.0 V IRMS= 0.0 A	1	\$0.01	0603 5 mm <sup>2</sup>

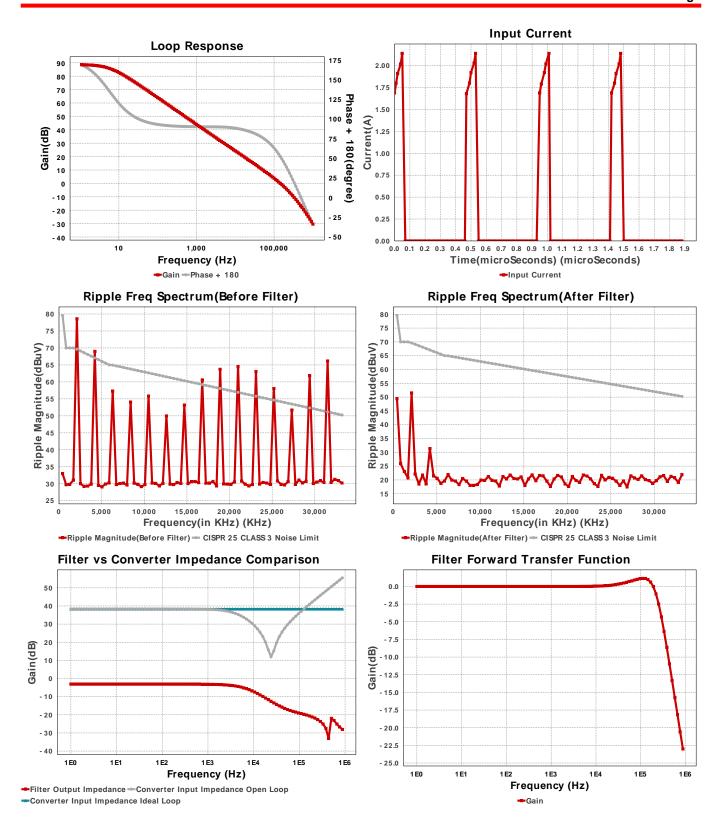
Name	Manufacturer	Part Number	Properties	Qty	Price	Footprint
L1	Bourns	SRN8040-3R3Y	L= 3.3 μH 21.0 mOhm	1	\$0.27	
						SRN8040 100 mm <sup>2</sup>
Lf_inpflt	TDK	NLCV32T-R10M-PFR	L= 100.0 nH 20.0 mOhm	1	\$0.10	NLCV32 13 mm <sup>2</sup>
Rd_inpflt	Panasonic	ERJ-3RSFR10V Series= ERJ-3R	Res= 100.0 mOhm Power= 100.0 mW Tolerance= 1.0%	1	\$0.03	0603 5 mm <sup>2</sup>
Rfbb	Vishay-Dale	CRCW040224K9FKED Series= CRCWe3	Res= 24.9 kOhm Power= 63.0 mW Tolerance= 1.0%	1	\$0.01	0402 3 mm <sup>2</sup>
Rfbt	Vishay-Dale	CRCW0402100KFKED Series= CRCWe3	Res= 100.0 kOhm Power= 63.0 mW Tolerance= 1.0%	1	\$0.01	0402 3 mm <sup>2</sup>
Rpg	Vishay-Dale	CRCW0402100KFKED Series= CRCWe3	Res= 100.0 kOhm Power= 63.0 mW Tolerance= 1.0%	1	\$0.01	0402 3 mm <sup>2</sup>
U1	Texas Instruments	LMR33630CDDAR	Switcher	1	\$0.75	
						DDA0008J 55 mm <sup>2</sup>

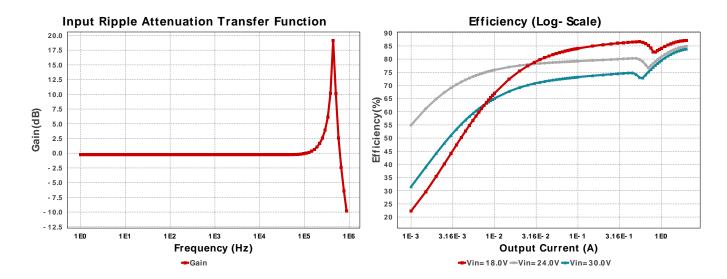












# Operating Values

# Name Value Category Description 1. Clin IRMS 728.66 d m	- 1				
2. Cin Pd 19.48 pt	#	Name	Value	Category	Description
3. Cinx IRMS 33.884 mA Capacitor Most ripple current 4. Cinx Pd 19.459 µW Capacitor FMS ripple current 5. Cout IRMS 178.286 mA Capacitor FMS ripple current 6. Cout IRMS 178.286 mA Capacitor FMS ripple current 7. Coutx IRMS 1.383 mA Capacitor 7. Coutx IRMS ripple Noise After51.63 dBuV FM Capacitor 7. Coutx IRMS ripple Noise After51.63 dBuV FM Capacitor 7. Coutx IRMS ripple Noise Current 7. Coutx IRMS ripple Noise After51.63 dBuV FM Capacitor 7. Coutx IRMS ripple Current 7. Coutx IRMS ripple Noise After51.63 dBuV FM Capacitor 7. Coutx IRMS ripple Current 7. Coutx IRMS ripple Ripple Current 7. Coutx IRMS ripple Current 7. Coutx Pd 57.348 Ripple Power 8. Coutx Pd 57.348 Ripple Ri	1.	Cin IRMS	728.604 mA	Capacitor	Input capacitor RMS ripple current
4. Cinx Pd 19.45 y W C. Cout IRNS 178.286 mA Capacitor 6. Cout IRNS 178.286 mA Capacitor 7. Coutx IRNS 1383 mA Capacitor 8. Coutx IRNS 1383 mA Capacitor 9. Input Ripple Noise Alter51.63 dBuV input Capacitor Capacitor Output capacitor Ext RNS ripple current 10. Input Ripple Noise Alter51.63 dBuV input Ripple Noise Alter filter at switching frequency input Ripple Ripple Roise after filter at switching frequency input Ripple Roise before filter at switching frequency input Ripple Rip	2.	Cin Pd	530.86 μW	Capacitor	Input capacitor power dissipation
5. Cout IRMS 178.286 mA Capacitor Output capacitor power dissipation Coutx IRMS 1.383 mA Capacitor Output capacitor power dissipation Input Ripple Noise After 51.63 dBuV EMI Noise Input Ripple Noise After filter at switching frequency Defore input filter Power Dissipation Noise Input Ripple Noise before filter at switching frequency Defore input filter Power Dissipation Noise Inmut Ripple Filter Power Dissipation Noise Inmut Ripple Filter Power Dissipation Noise Inmut Ripple Ritter Down Dissipation Dis	3.	Cinx IRMS	33.884 mA	Capacitor	Bulk capacitor RMS ripple current
5. Cout IRMS 178.286 mA Capacitor Output capacitor power dissipation Coutx IRMS 1.383 mA Capacitor Output capacitor power dissipation Input Ripple Noise After 51.63 dBuV EMI Noise Input Ripple Noise After filter at switching frequency Defore input filter Power Dissipation Noise Input Ripple Noise before filter at switching frequency Defore input filter Power Dissipation Noise Inmut Ripple Filter Power Dissipation Noise Inmut Ripple Filter Power Dissipation Noise Inmut Ripple Ritter Down Dissipation Dis	4.	Cinx Pd	19.459 μW	Capacitor	Bulk capacitor power dissipation
7. Coutx IRMS 1.383 m/A Capacitor S. Coutx Pd 57.348 n/W Capacitor Joven Pd 78.6 dBuV EMI Noise Imput Ripple Noise After 51.63 dBuV Imput Ripple Noise After filter at switching frequency Imput Ripple Noise Defore input filter Pd 3.158 m/W EMI Noise Imput Ripple Noise Defore filter at switching frequency Imput Ripple Noise Defore filter at switching frequency Imput Ripple Polise Defore Polise Polise Defore Polise Imput Ripple Polise Defore Polise P	5.	Cout IRMS			
8. Coutx Pd 57.348 nW End Noise Input Ripple Noise After51.63 dBuV input Ripple Noise After filter at switching frequency leaf or input filter input Ripple Noise before filter at switching frequency before input filter input Ripple R	6.	Cout Pd	47.679 μW	Capacitor	Output capacitor power dissipation
9. Input Ripple Noise After 51.63 dBuV input Ripple Noise after filter at switching frequency input filter 10. Input Ripple Noise P 78.6 dBuV before input filter P 3.158 mW EMI Noise CISPR Standards CISPR CISPR CISPR Standards CISPR CISPR Standard CISPR CISPR CISPR Standard CISPR CISPR CISPR Standard CISPR CI	7.	Coutx IRMS	1.383 mA	Capacitor	Output capacitor_x RMS ripple current
input Ripple Noise 78.6 dBuV before input filter  11. Input Ripple Riter Pd 3.158 mW EMI Noise Input Ripple Filter Power Dissipation  12. Noise Ilmits defined by 69.63 dBuV EMI Noise Ilmits for CLASS 3 of CISPR 25 standard CISPR Standards  13. Ic Ipk 2. 311 A IC Peak switch current in IC [C power dissipation]  14. IC Pd 1.836 W IC IC [C power dissipation]  15. IC TJ 96.724 degC IC IC [D prover dissipation]  16. IC Tolerance 15.0 mV IC IC Effective IC Junction-ton-Ambient Thermal Resistance  17. ICThetaJA Effective 20.0 degC/W IC Effective IC Junction-ton-Ambient Thermal Resistance  18. In Avg 397.39 mA IC Average input current in IC Average input current in IC Peak Switch Current in IC	8.	Coutx Pd	57.348 nW	Capacitor	Output capacitor_x power loss
Input Ripple Noise   As of Bul   EMI Noise   Input Ripple Noise before filter at switching frequency	9.		r51.63 dBuV	EMI Noise	Input Ripple Noise after filter at switching frequency
11.     Input Ripple filter Pd     3.158 mW     EMI Noise     Input Ripple Filter Power Dissipation       12.     Noise limits defined by G9.63 dBuV     EMI Noise     Noise limits for CLASS 3 of CISPR 25 standard       13.     IC IpK     2.311 A     IC     Peak switch current in IC       14.     IC Pd     1.836 W     IC     IC power dissipation       15.     IC Tj     96.724 degC     IC     IC junction temperature       16.     IC Tolerance     15.0 mV     IC     IC Feedback Tolerance       17.     ICThetaJA Effective     20.0 degC/W     IC     Effective IC Junction-to-Ambient Thermal Resistance       18.     Iin Avg     397.39 mA     IC     Average input current       19.     Ipp percentage     31.12 %     Inductor       10.     L Ipg     622.39 mA     Inductor     Inductor imple current percentage (with respect to average inductor current)       20.     L Ipg     622.39 mA     Inductor     Inductor power dissipation       21.     L Pd     84.678 mW     Inductor     Input capacitor power dissipation       22.     Cin Pd     19.459 µW     Power     Output capacitor power dissipation       23.     Cinx Pd     19.459 µW     Power     Output capacitor power dissipation       24.     Cout Pd     76.79	10.	Input Ripple Noise	78.6 dBuV	EMI Noise	Input Ripple Noise before filter at switching frequency
12. Noise limits defined by 69.63 dBuV CISPR Standards   CISPR Standards     13. IC lpk	11.		3.158 mW	EMI Noise	Input Ripple Filter Power Dissipation
13.   C   Dpk		Noise limits defined by	69.63 dBuV	EMI Noise	· · · · ·
14.   IC Pd	13.	IC lpk	2.311 A	IC	Peak switch current in IC
15.         IC Tj         96.724 degC         IC         IC junction temperature           16.         IC Tolerance         15.0 mV         IC         IC Feedback Tolerance           17.         ICThetaJA Effective         20.0 degC/W         IC         Effective IC Junction-to-Ambient Thermal Resistance           18.         lin Avg         397.39 mA         IC         Average input current           19.         lpp percentage         31.12 %         Inductor Inductor ripple current percentage (with respect to average inductor current)           20.         L Ipp         622.39 mA         Inductor         Peak-to-peak inductor ripple current           21.         L Pd         84.678 mW         Inductor         Peak-to-peak inductor ripple current           22.         Cin Pd         530.86 μW         Power         Input capacitor power dissipation           23.         Cinx Pd         19.459 μW         Power         Duty capacitor power dissipation           24.         Cout Pd         47.679 μW         Power         Output capacitor power dissipation           25.         Coutx Pd         57.348 nW         Power         Output capacitor power dissipation           26.         IC Pd         1.836 W         Power         IC power dissipation           27.		•	1.836 W		IC power dissipation
16.         IC Tolerance         15.0 mV         IC         IC Feedback Tolerance           17.         ICThetaJA Effective         20.0 degC/W         IC         Effective IC Junction-to-Ambient Thermal Resistance           18.         lin Avg         397.39 mA         IC         Average input current           19.         lpp percentage         31.12 %         Inductor         Inductor ripple current percentage (with respect to average inductor current)           20.         L Ipp         622.39 mA         Inductor         Peak-to-peak inductor ripple current Inductor power dissipation           21.         L Pd         84.678 mW         Inductor         Inductor power dissipation           22.         Cin Pd         530.86 µW         Power         Input capacitor power dissipation           23.         Cinx Pd         19.459 µW         Power         Bulk capacitor power dissipation           24.         Cout Pd         47.679 µW         Power         Output capacitor power dissipation           25.         Cout Pd         57.348 mW         Power         Ucp unt Ripple filter Pd         3.158 mW           26.         IC Pd         1.836 W         Power         Input Ripple filter Power Dissipation           29.         Total Pd         1.924 W         Power         Inductor	15.	IC Tj	96.724 degC	IC	· ·
17.     ICThetaJA Effective     20.0 degC/W     IC     Effective IC Junction-to-Ambient Thermal Resistance       18.     lin Avg     397.39 mA     IC     Average input current       19.     lpp percentage     31.12 %     Inductor     Inductor ripple current percentage (with respect to average inductor current)       20.     L Ipp     622.39 mA     Inductor     Peak-to-peak inductor ripple current       21.     L Pd     84.678 mW     Inductor     Inductor power dissipation       22.     Cin Pd     530.86 μW     Power     Input capacitor power dissipation       23.     Cinx Pd     19.459 μW     Power     Output capacitor power dissipation       24.     Cout Pd     47.679 μW     Power     Output capacitor power dissipation       25.     Coutx Pd     57.348 nW     Power     Output capacitor x power loss       26.     IC Pd     1.836 W     Power     IC power dissipation       27.     Input Ripple filter Pd     3.158 mW     Power     Input Ripple Filter Power Dissipation       28.     L Pd     84.678 mW     Power     Total Power Dissipation       30.     BOM Count     17     System     Total Power Dissipation       31.     Cross Freq     145.199 kHz     System     Duty cycle       32.     Duty		•	<u> </u>		· ·
19.   Ipp percentage   31.12 %	17.	ICThetaJA Effective			Effective IC Junction-to-Ambient Thermal Resistance
19.	18.	lin Avg	397.39 mA	IC	Average input current
20.         L Ipp         622.39 mA         Inductor         Peak-to-peak inductor ripple current Inductor power dissipation           21.         L Pd         84.678 mW         Power Inductor power dissipation           22.         Cin Pd         530.86 μW         Power Input capacitor power dissipation           23.         Cinx Pd         19.459 μW         Power Bulk capacitor power dissipation           24.         Cout Pd         47.679 μW         Power Output capacitor power dissipation           25.         Coutx Pd         57.348 nW         Power Output capacitor power dissipation           26.         Ic Pd         1.836 W         Power Output capacitor power dissipation           27.         Input Ripple filter Pd         3.158 mW         Power Inductor power dissipation           28.         L Pd         84.678 mW         Power Inductor power dissipation           30.         BOM Count         17         System Total Design BOM count           31.         Cross Freq         145.199 kHz         System Bode plot crossover frequency           32.         Duty Cycle         17.433 %         System Information           33.         Efficiency         83.859 %         System Information           35.         Frequency         2.1 MHz         System Information </td <td></td> <td></td> <td>31.12 %</td> <td>Inductor</td> <td>., , , , ,</td>			31.12 %	Inductor	., , , , ,
21. L Pd 84.678 mW Inductor Power dissipation   22. Cin Pd 530.86 µW Power Input capacitor power dissipation   23. Cinx Pd 19.459 µW Power Output capacitor power dissipation   24. Cout Pd 47.679 µW Power Output capacitor power dissipation   25. Coutx Pd 57.348 nW Power Output capacitor power dissipation   26. IC Pd 1.836 W Power Output capacitor power dissipation   27. Input Ripple filter Pd 3.158 mW Power Input Ripple Filter Power Dissipation   28. L Pd 84.678 mW Power Inductor power dissipation   29. Total Pd 1.924 W Power Inductor power dissipation   30. BOM Count 17 System Information   31. Cross Freq 145.199 kHz System Information   32. Duty Cycle 17.433 % System Information   33. Efficiency 83.859 % System Information   34. FootPrint 313.0 mm² System Information   35. Frequency 2.1 MHz System System Information   36. Gain Marg -17.025 dB System Information   37. Iout 2.0 A System Information   38. Low Freq Gain 88.564 dB System Gain at 1Hz	20.	L lpp	622.39 mA	Inductor	,
22. Cin Pd 530.86 µW Power Input capacitor power dissipation 23. Cinx Pd 19.459 µW Power Bulk capacitor power dissipation 24. Cout Pd 47.679 µW Power Output capacitor power dissipation 25. Coutx Pd 57.348 nW Power Output capacitor x power loss 26. IC Pd 1.836 W Power IC power dissipation 27. Input Ripple filter Pd 3.158 mW Power Input Ripple filter Power Dissipation 28. L Pd 84.678 mW Power Input Ripple Filter Power Dissipation 29. Total Pd 1.924 W Power Total Power Dissipation 29. Total Pd 1.924 W Power Total Power Dissipation 29. Total Pd 1.924 W Power Total Power Dissipation 29. Duty Cycle 17.433 % System Information 29. Duty Cycle 17.433 % System Information 29. Total Power Dissipation 29. System Information 29. Total Power Dissipation 29. System Information 29. Total Power Dissipation 20. System Information 29. System 20. Syst			84.678 mW	Inductor	·
24. Cout Pd 47.679 μW Power Output capacitor power dissipation 25. Coutx Pd 57.348 nW Power Output capacitor_x power loss 26. IC Pd 1.836 W Power IC power dissipation 27. Input Ripple filter Pd 3.158 mW Power Input Ripple Filter Power Dissipation 28. L Pd 84.678 mW Power Inductor power dissipation 29. Total Pd 1.924 W Power Inductor power dissipation 30. BOM Count 17 System Total Power Dissipation 31. Cross Freq 145.199 kHz System Information 32. Duty Cycle 17.433 % System Duty cycle Information 33. Efficiency 83.859 % System Steady state efficiency Information 34. FootPrint 313.0 mm² System Information 35. Frequency 2.1 MHz System Switching frequency Information 36. Gain Marg -17.025 dB System Information 37. Iout 2.0 A System Iout operating point 38. Low Freq Gain 88.564 dB System Gain at 1Hz	22.	Cin Pd	530.86 μW	Power	Input capacitor power dissipation
25. Coutx Pd 57.348 nW Power Output capacitor_x power loss 26. IC Pd 1.836 W Power IC power dissipation 27. Input Ripple filter Pd 3.158 mW Power Input Ripple Filter Power Dissipation 28. L Pd 84.678 mW Power Inductor power dissipation 29. Total Pd 1.924 W Power Total Power Dissipation 29. Total Pd 1.924 W Power Total Power Dissipation 30. BOM Count 17 System Total Design BOM count 31. Cross Freq 145.199 kHz System Information 32. Duty Cycle 17.433 % System Information 33. Efficiency 83.859 % System Information System Information 34. FootPrint 313.0 mm² System Information 35. Frequency 2.1 MHz System Information 36. Gain Marg -17.025 dB System Information 37. lout 2.0 A System Information 39. Low Freq Gain 88.564 dB System Gain at 1Hz	23.	Cinx Pd	19.459 μW	Power	Bulk capacitor power dissipation
26. IC Pd 1.836 W Power IC power dissipation 27. Input Ripple filter Pd 3.158 mW Power Input Ripple Filter Power Dissipation 28. L Pd 84.678 mW Power Inductor power dissipation 29. Total Pd 1.924 W Power Total Power Dissipation 30. BOM Count 17 System Information 31. Cross Freq 145.199 kHz System Information 32. Duty Cycle 17.433 % System Information 33. Efficiency 83.859 % System Information 34. FootPrint 313.0 mm² System Information 35. Frequency 2.1 MHz System Information 36. Gain Marg -17.025 dB System Information 37. lout 2.0 A System Information 38. Low Freq Gain 88.564 dB System Gain at 1Hz	24.	Cout Pd	47.679 μW	Power	Output capacitor power dissipation
27.Input Ripple filter Pd 28.3.158 mW 84.678 mWPower Power PowerInput Ripple Filter Power Dissipation28.L Pd 30.84.678 mW 1.924 WPower Power Power System InformationInductor power dissipation30.BOM Count17System InformationTotal Power Dissipation31.Cross Freq145.199 kHzSystem InformationBode plot crossover frequency32.Duty Cycle17.433 %System InformationDuty cycle33.Efficiency83.859 %System InformationSteady state efficiency34.FootPrint313.0 mm²System InformationTotal Foot Print Area of BOM components Information35.Frequency2.1 MHzSystem InformationSwitching frequency36.Gain Marg-17.025 dBSystem InformationBode Plot Gain Margin37.lout2.0 ASystem InformationIout operating point38.Low Freq Gain88.564 dBSystemGain at 1Hz	25.	Coutx Pd	57.348 nW	Power	Output capacitor_x power loss
28. L Pd 84.678 mW Power Inductor power dissipation 29. Total Pd 1.924 W Power Total Power Dissipation 30. BOM Count 17 System Total Design BOM count 31. Cross Freq 145.199 kHz System Bode plot crossover frequency Information 32. Duty Cycle 17.433 % System Information 33. Efficiency 83.859 % System Steady state efficiency Information 34. FootPrint 313.0 mm² System Information 35. Frequency 2.1 MHz System Switching frequency Information 36. Gain Marg -17.025 dB System Information 37. lout 2.0 A System Iout operating point 38. Low Freq Gain 88.564 dB System Gain at 1Hz	26.	IC Pd	1.836 W	Power	IC power dissipation
29. Total Pd 1.924 W Power Total Power Dissipation 30. BOM Count 17 System Total Design BOM count  31. Cross Freq 145.199 kHz System Bode plot crossover frequency Information 32. Duty Cycle 17.433 % System Information 33. Efficiency 83.859 % System System Information 34. FootPrint 313.0 mm² System Information 35. Frequency 2.1 MHz System Switching frequency Information 36. Gain Marg -17.025 dB System Information 37. lout 2.0 A System Information 38. Low Freq Gain 88.564 dB System Gain at 1Hz	27.	Input Ripple filter Pd	3.158 mW	Power	Input Ripple Filter Power Dissipation
30. BOM Count  17	28.	L Pd	84.678 mW	Power	Inductor power dissipation
Information   System   Bode plot crossover frequency   Information	29.	Total Pd	1.924 W	Power	Total Power Dissipation
31. Cross Freq 145.199 kHz System Information 22. Duty Cycle 17.433 % System Information 23. Efficiency 83.859 % System Steady state efficiency Information 24. FootPrint 313.0 mm² System Information 25. Frequency 2.1 MHz System Switching frequency Information 26. Gain Marg -17.025 dB System Bode Plot Gain Margin Information 27. lout 2.0 A System Information 28. Low Freq Gain 88.564 dB System Gain at 1Hz	30.	BOM Count	17	•	Total Design BOM count
Information 33. Efficiency 83.859 % System Information System Steady state efficiency System Information 34. FootPrint 313.0 mm² System Information System Information System Switching frequency Information 36. Gain Marg -17.025 dB System Information System Switching frequency Information System In	31.	Cross Freq	145.199 kHz	System	Bode plot crossover frequency
33. Efficiency 83.859 % System Information 34. FootPrint 313.0 mm² System Total Foot Print Area of BOM components Information 35. Frequency 2.1 MHz System Switching frequency Information 36. Gain Marg -17.025 dB System Bode Plot Gain Margin Information 37. lout 2.0 A System lout operating point Information 38. Low Freq Gain 88.564 dB System Gain at 1Hz	32.	Duty Cycle	17.433 %	•	Duty cycle
34. FootPrint  313.0 mm²  System Information  35. Frequency  2.1 MHz  System Switching frequency Information  36. Gain Marg  -17.025 dB  System Bode Plot Gain Margin Information  37. lout  2.0 A  System lout operating point Information  38. Low Freq Gain  88.564 dB  System Gain at 1Hz	33.	Efficiency	83.859 %	System	Steady state efficiency
35. Frequency 2.1 MHz System Switching frequency Information 36. Gain Marg -17.025 dB System Bode Plot Gain Margin Information 37. lout 2.0 A System lout operating point Information 38. Low Freq Gain 88.564 dB System Gain at 1Hz	34.	FootPrint	313.0 mm <sup>2</sup>	System	Total Foot Print Area of BOM components
36. Gain Marg -17.025 dB System Bode Plot Gain Margin Information 37. lout 2.0 A System lout operating point Information 38. Low Freq Gain 88.564 dB System Gain at 1Hz	35.	Frequency	2.1 MHz	System	Switching frequency
37. lout 2.0 A System lout operating point Information 38. Low Freq Gain 88.564 dB System Gain at 1Hz	36.	Gain Marg	-17.025 dB	System	Bode Plot Gain Margin
38. Low Freq Gain 88.564 dB System Gain at 1Hz	37.	lout	2.0 A	System	lout operating point
	38.	Low Freq Gain	88.564 dB	System	Gain at 1Hz

#	Name	Value	Category	Description
39.	Mode	CCM	System Information	Conduction Mode
40.	Phase Marg	52.455 deg	System Information	Bode Plot Phase Margin
41.	Pout	10.0 W	System Information	Total output power
42.	Total BOM	\$2.36	System Information	Total BOM Cost
43.	Vin	30.0 V	System Information	Vin operating point
44.	Vin p-p	29.878 mV	System Information	Peak-to-peak input voltage
45.	Vout	5.0 V	System Information	Operational Output Voltage
46.	Vout Actual	5.016 V	System Information	Vout Actual calculated based on selected voltage divider resistors
47.	Vout Tolerance	3.142 %	System Information	Vout Tolerance based on IC Tolerance (no load) and voltage divider resistors if applicable
48.	Vout p-p	2.922 mV	System Information	Peak-to-peak output ripple voltage

# **Design Inputs**

Name	Value	Description	
lout	2.0	Maximum Output Current	
VinMax	30.0	Maximum input voltage	
VinMin	18.0	Minimum input voltage	
Vout	5.0	Output Voltage	
base_pn	LMR33630C-SOIC	Base Product Number	
source	DC	Input Source Type	
Та	60.0	Ambient temperature	

# WEBENCH® Assembly

#### Component Testing

Some published data on components in datasheets such as Capacitor ESR and Inductor DC resistance is based on conservative values that will guarantee that the components always exceed the specification. For design purposes it is usually better to work with typical values. Since this data is not always available it is a good practice to measure the Capacitance and ESR values of Cin and Cout, and the inductance and DC resistance of L1 before assembly of the board. Any large discrepancies in values should be electrically simulated in WEBENCH to check for instabilities and thermally simulated in WebTHERM to make sure critical temperatures are not exceeded.

### Soldering Component to Board

If board assembly is done in house it is best to tack down one terminal of a component on the board then solder the other terminal. For surface mount parts with large tabs, such as the DPAK, the tab on the back of the package should be pre-tinned with solder, then tacked into place by one of the pins. To solder the tab town to the board place the iron down on the board while resting against the tab, heating both surfaces simultaneously. Apply light pressure to the top of the plastic case until the solder flows around the part and the part is flush with the PCB. If the solder is not flowing around the board you may need a higher wattage iron (generally 25W to 30W is enough).

### Initial Startup of Circuit

It is best to initially power up the board by setting the input supply voltage to the lowest operating input voltage 18.0V and set the input supply's current limit to zero. With the input supply off connect up the input supply to Vin and GND. Connect a digital volt meter and a load if needed to set the minimum lout of the design from Vout and GND. Turn on the input supply and slowly turn up the current limit on the input supply. If the voltage starts to rise on the input supply continue increasing the input supply current limit while watching the output voltage. If the current increases on the input supply, but the voltage remains near zero, then there may be a short or a component misplaced on the board. Power down the board and visually inspect for solder bridges and recheck the diode and capacitor polarities. Once the power supply circuit is operational then more extensive testing may include full load testing, transient load and line tests to compare with simulation results.

### Load Testing

The setup is the same as the initial startup, except that an additional digital voltmeter is connected between Vin and GND, a load is connected between Vout and GND and a current meter is connected in series between Vout and the load. The load must be able to handle at least rated output power + 50% (7.5 watts for this design). Ideally the load is supplied in the form of a variable load test unit. It can also be done in the form of suitably large power resistors. When using an oscilloscope to measure waveforms on the prototype board, the ground leads of the oscilloscope probes should be as short as possible and the area of the loop formed by the ground lead should be kept to a minimum. This will help reduce ground lead inductance and eliminate EMI noise that is not actually present in the circuit.



### **Design Assistance**

- 1. Master key: D92E1EB0221A07D6[v1]
- 2. LMR33630C-SOIC Product Folder: http://www.ti.com/product/LMR33630: contains the data sheet and other resources.

#### Important Notice and Disclaimer

TI provides technical and reliability data (including datasheets), design resources (including reference designs), application or other design advice, web tools, safety information, and other resources AS IS and with all faults, and disclaims all warranties. These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

Providing these resources does not expand or otherwise alter TI's applicable Terms of Sale or other applicable terms available either on ti.com or provided in conjunction with TI products.